

FGH30N60LSD 600 V, 30 A PT IGBT

Features

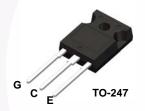
- Low Saturation Voltage: $V_{CE(sat)} = 1.1 \text{ V} @ I_C = 30 \text{ A}$
- · High Input Impedance
- Low Conduction Loss

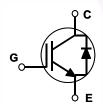
Applications

· Solar Inverter, UPS

General Description

Using Fairchild's advanced PT technology, the FGA30N60LSD IGBT offers superior conduction performances, which offer the optimum performance for medium switching application such as solar inverter, UPS applications where low conduction losses are the most important factor.





Absolute Maximum Ratings

Symbol	Description		Ratings	Unit	
V _{CES}	Collector-Emitter Voltage		600	V	
V _{GES}	Gate-Emitter Voltage	mitter Voltage ± 20		V	
	Collector Current	@ T _C = 25°C	60	Α	
I _C	Collector Current	@ T _C = 100°C	30	A	
I _{CM (1)}	Pulsed Collector Current	90		A	
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave		150	А	
D	Maximum Power Dissipation @ T _C = 25°C		480	W	
P_{D}	Maximum Power Dissipation @ $T_C = 100^{\circ}C$		192	W	
TJ	Operating Junction Temperature		-55 to +150	°C	
T _{stg}	Storage Temperature Range		-55 to +150		
T _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	°C		

Notes

(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction-to-Case		0.26	°C/W
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction-to-Case		0.92	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		40	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGH30N60LSDTU	FGH30N60LSD	TO-247	Tube	N/A	N/A	30

Electrical Characteristics of the IGBT $T_C = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV _{CES}	Collector-Emitter Breakdown Voltage	$V_{GE} = 0 \text{ V}, I_{C} = 250 \text{ uA}$	600			V
ΔB _{VCES} / ΔT _J	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0 \text{ V, } I_{C} = 250 \text{ uA}$		0.6		V/°C
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$			250	uA
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}$, $V_{CE} = 0 V$			±250	nA
On Charac	teristics					
V _{GE(th)}	G-E Threshold Voltage	$I_{C} = 250 \text{ uA}, V_{CE} = V_{GE}$	4.0	5.5	7.0	V
OL(III)		$I_C = 30 \text{ A}, V_{GE} = 15 \text{ V}$		1.1	1.4	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 30 A, V _{GE} = 15 V, T _C = 125°C		1.0		V
		I _C = 60 A, V _{GE} = 15 V		1.3		V
Dynamic C	haracteristics					
C _{ies}	Input Capacitance			3550		pF
C _{oes}	Output Capacitance	$V_{CE} = 30 \text{ V}, V_{GE} = 0 \text{ V},$ f = 1 MHz		245		pF
C _{res}	Reverse Transfer Capacitance	1 = 1 101112		90		pF
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time			18		ns
t _r	Rise Time	-		46		ns
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 400 V, I _C = 30 A,		250		ns
t _f	Fall Time	$R_G = 6.8 \Omega$, $V_{GE} = 15 V$,		1.3	2.0	us
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 25°C		1.1		mJ
E _{off}	Turn-Off Switching Loss			21	/	mJ
t _{d(on)}	Turn-On Delay Time			17		ns
t _r	Rise Time	-		45	\	ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 400 \text{ V}, I_{C} = 30 \text{ A},$		270		ns
t _f	Fall Time	$R_G = 6.8 \Omega$, $V_{GE} = 15 V$,		2.6		us
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 125°C		1.1		mJ
E _{off}	Turn-Off Switching Loss			36		mJ
Qg	Total Gate Charge			225		nC
Q _{ge}	Gate-Emitter Charge	$V_{CE} = 600 \text{ V}, I_{C} = 30 \text{ A},$ $V_{GE} = 15 \text{ V}$		30		nC
Q _{gc}	Gate-Collector Charge	- VGE - 10 V		105		nC
L _e	Internal Emitter Inductance	Measured 5mm from PKG		7		nΗ

Electrical Characteristics of the Diode $T_C = 25^{\circ}C$ unless otherwise noted

Parameter	Conditions	Min.	Тур.	Max	Unit	
V _{FM}	I _F = 15 A I _F = 15 A	T _C = 25 °C T _C = 125 °C	-	1.8 1.6	2.2	V V
I _{RM}	V _R = 600 V	T _C = 25 °C	-	-	100	μА
t _{rr}	$I_F = 1$ A, $di_F/dt = 100$ A/ μ s, $V_R = 30$ V $I_F = 15$ A, $di_F/dt = 100$ A/ μ s, $V_R = 390$ V	$T_C = 25 ^{\circ}C$ $T_C = 25 ^{\circ}C$	-	-	35 40	ns ns
t _a t _b Q _{rr}	$I_F = 15 \text{ A}, \text{ di}_F/\text{dt} = 100 \text{ A/}\mu\text{s}, \text{ V}_R = 390 \text{ V}$	$T_C = 25 ^{\circ}C$ $T_C = 25 ^{\circ}C$ $T_C = 25 ^{\circ}C$	-	18 13 27.5	- - -	ns ns nC

Typical Performance Characteristics

Figure 1. Typical Output Characteristics

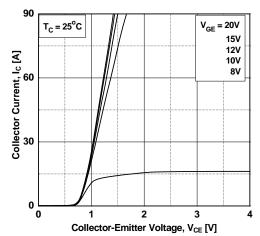


Figure 3. Typical Saturation Voltage Characteritics

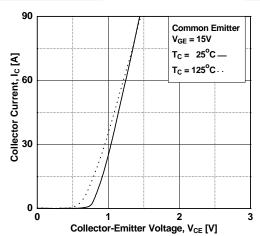


Figure 5. Saturation Voltage vs. Case
Temperature at Variant Current Level

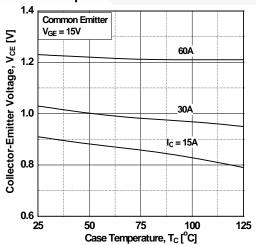


Figure 2. Typical Saturation Voltage Characteristics

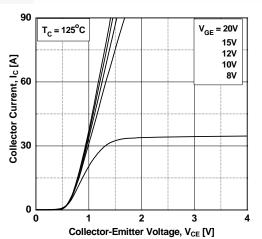


Figure 4. Transfer characteristics

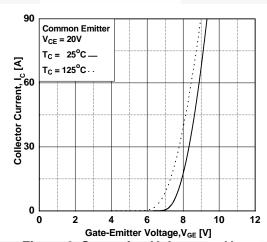
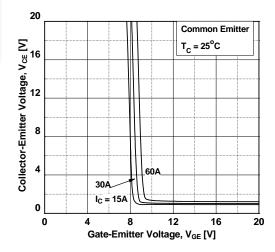


Figure 6. Saturation Voltage vs. Vge



Typical Performance Characteristics (Continued)

Figure 7. Saturation Voltage vs. Vge

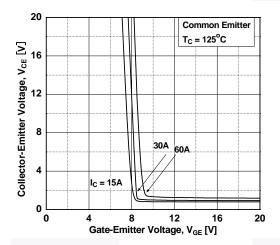


Figure 9. Gate Charge Characteristics

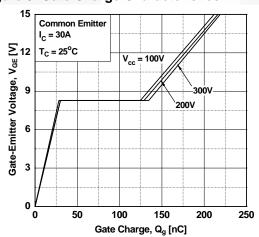


Figure 11. Load Current Vs. Frequency

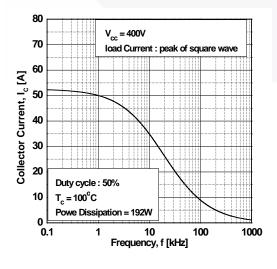


Figure 8. Capacitance characteristics

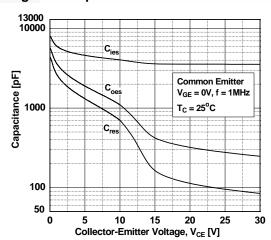


Figure 10. SOA Characteeristics

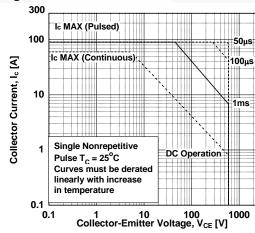
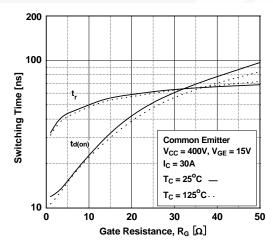


Figure 12. Turn-On Characteristics vs.
Gate Resistance



Typical Performance Characteristics (Continued)

Figure 13. Turn-Off Characteristics vs. **Gate Resistance**

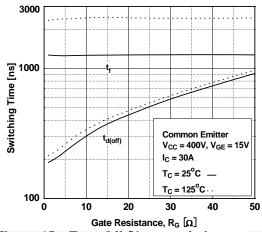


Figure 15. Turn-Off Characteristics vs. **Collector Current**

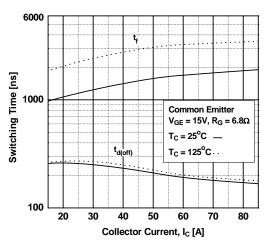


Figure 17.Switching Loss vs Collector Current

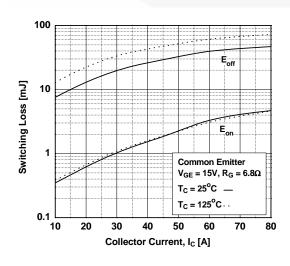


Figure 14. Turn-On Characteristics vs. **Collector Current**

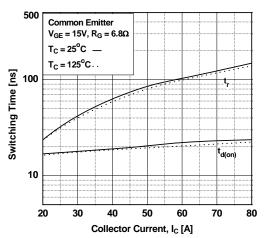
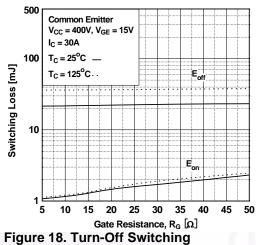
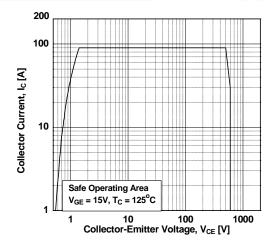


Figure 16. Switching Loss vs **Gate Resistance**



SOA Characteristics





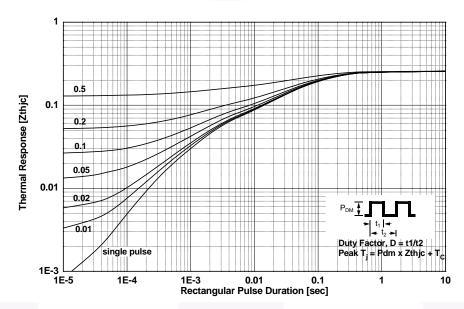


Figure 20. Forward Characteristics

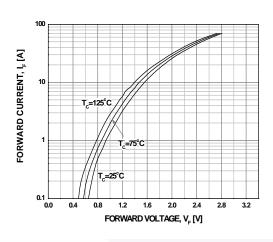


Figure 21. Reverse Current

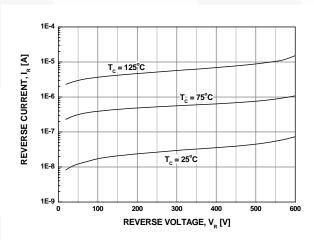
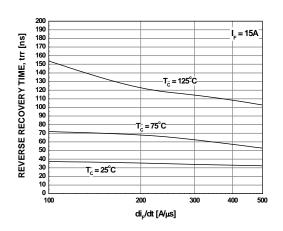


Figure 22. Reverse Recovery Time



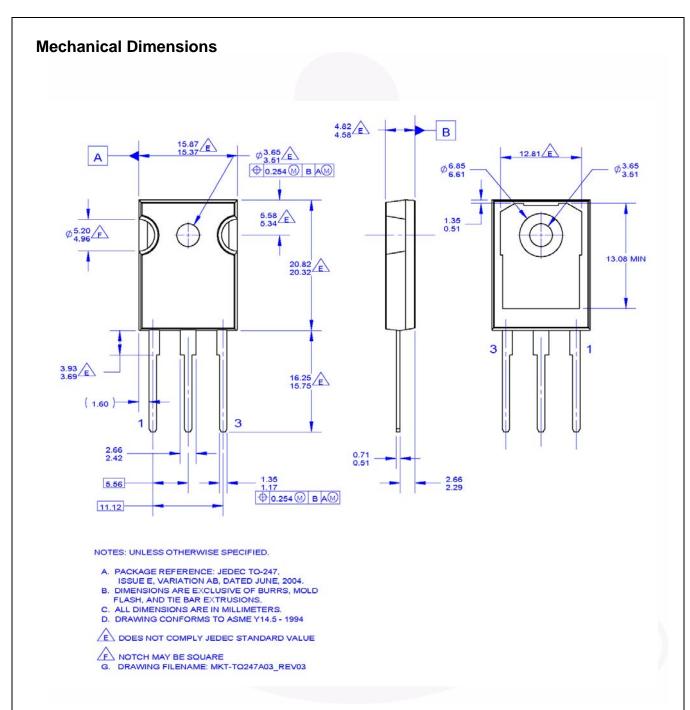


Figure 23. TO-247 3L - TO-247, MOLDED, 3 LEAD, JEDEC VARIATION AB

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